

JL7032F Datasheet

Zhuhai Jieli Technology Co.,LTD

Version 2.1

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Revision History

Date	Revision	Description
2023.09.16	V1.0	Initial Release
2023.11.06	V1.1	Add IC Marking Information Update BT_Features Update FM Characteristics
2023.12.04	V1.2	Add FM test conditions
2024.07.12	V1.3	Use New Datasheet Format Update DSP Audio Processing_Feature(Support Hi-Res Audio) Add PIN PC6 Note(PC6 input can not be Low in power on) Update IC Marking Information
2024.07.26	V1.4	Update Peripherals_Features(Support High speed USB2.0) Update Pin Description(Update FMIP IO Type)
2024.08.22	V1.5	Update BT characteristics
2024.09.27	V1.6	Update Pin Description(Update FMIP IO Type)
2024.11.26	V2.0	Update Feature_Audio(Add I ² S&TDM&SPDIF&PDM Description) Update Feature_Peripherals(Add IR RX)
2025.01.16	V2.1	Update Features_Bluetooth Update Block Diagram

Table of Contents

Revision History	1
Table of Contents	2
JL7032F Features	3
1 Block Diagram	5
2 Pin Definition	6
2.1 Pin Assignment	6
2.2 Pin Description	7
3 Electrical Characteristics	10
3.1 Absolute Maximum Ratings	10
3.2 ESD Ratings	10
3.3 PMU Characteristics	10
3.4 Battery Charge	11
3.5 IO Characteristics	11
3.6 Audio DAC Characteristics	13
3.7 Audio ADC Characteristics	15
3.8 BT Characteristics	16
3.9 FM Characteristics	17
4 Package Information	18
4.1 QFN40_5x5mm	18
5 IC Marking Information	19
6 Solder-Reflow Condition	20

JL7032F Features

SYSTEM

- Dual Core 32bit DSP 320MHz
- With IEEE754 Single precision FPU
- Support FFT/MATRIX/MATH
- 2 x I-cache and D-cache
- Support SDTAP/EMU
- On-chip SRAM 528kbyte
- Support MMU
- Support MPU
- Support External PSRAM
- Built-In Flash
- 24MHz crystal oscillator
- Internal RC oscillator, PLL

DSP Audio Processing

- SBC/AAC/LDAC/LHDC/LC3/CVSD/mSBC codec
- mSBC voice codec supported for BT phone
- PLC for voice processing
- Multi-MIC ENC
- Multi-band DRC
- Multi-band EQ
- Support spatial sound
- Support Hi-Res Audio

Audio

- 4 x 24bit DAC
 - ❖ SNR 113dB
 - ❖ Noise 3uVrms
 - ❖ Supports differential mode
 - ❖ Supports VCMO mode
 - ❖ Sampling rate 8~96kHz
- 4 x 24bit ADC
 - ❖ SNR 105dB
 - ❖ Sampling rate 8~48kHz
 - ❖ Support AMUX
- 2 x I²S AUDIO Master/Slave interface
 - ❖ Sampling rate 8~384kHz
 - ❖ Support TX and RX
 - ❖ Support multi-slot mode(TDM)
- 1 x SPDIF AUDIO Master/Slave interface
 - ❖ Sampling rate 8~384kHz

- ❖ Support TX and RX

- 1 x PDM AUDIO Slave interface

- ❖ Sampling rate 8~192kHz

- ❖ 4 x DMIC input

Bluetooth

- Dual-mode BT6.0 with LE Audio (DN Q332415)
- Support AoA/AoD
- Support LE audio BIS/CIS
- Support long range BLE
- Maximum transmitting power 10dBm
- Receiver sensitivity
 - ❖ -95 dBm @BR
 - ❖ -95 dBm @EDR 1/4 DQPSK
 - ❖ -87 dBm @EDR 8DPSK

Peripherals

- 1 x High speed USB2.0
- 2 x SD host controller
- 6 x Multi-function 32bit timer
- 3 x UART interface
- 1 x I²C Master/Slave interface
- 3 x SPI Master/Slave interface
- 3 x QDEC
- 1 x 10bit ADC(11 Channels)
- 19 x GPIO Support function remapping
- 1 x VLCD driver
- 3 x Light strip controller
- 12 x MCPWM
- 2 x LP_Touch with low power wake up
- 1 x IR RX

FM

- FM RX sensitivity minimum 4dBuV, Support mono/stereo

PMU

- Integrated battery charger up to 350mA
- 1 x Buck DC-DC converter
- Support temperature sensor

- VPWR range 4.5V to 5.5V
- VBAT range 2.7V to 4.5V
- IOVDD range 2.2V to 3.4V

Packages

- QFN40(5mm*5mm)

Temperature

- Operating temperature
TC = -20℃ to +85℃ (standard range)
TC = -40℃ to +105℃ (extended range)
- Storage temperature -65℃ to +150℃

Applications

- Bluetooth Speaker
- Bluetooth Stereo Headsets and Headphones
- Bluetooth Recording Pen

1 Block Diagram

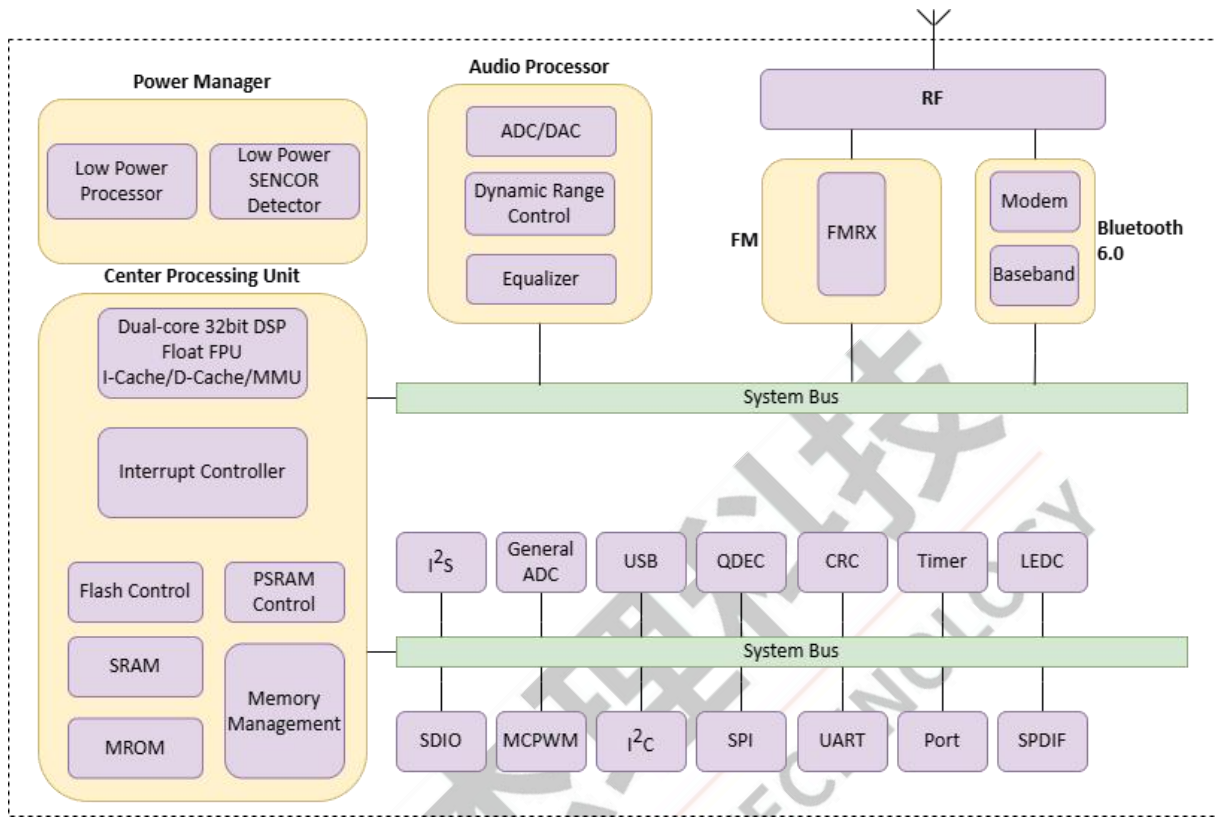


Figure 1-1 JL7032F Block Diagram

2 Pin Definition

2.1 Pin Assignment

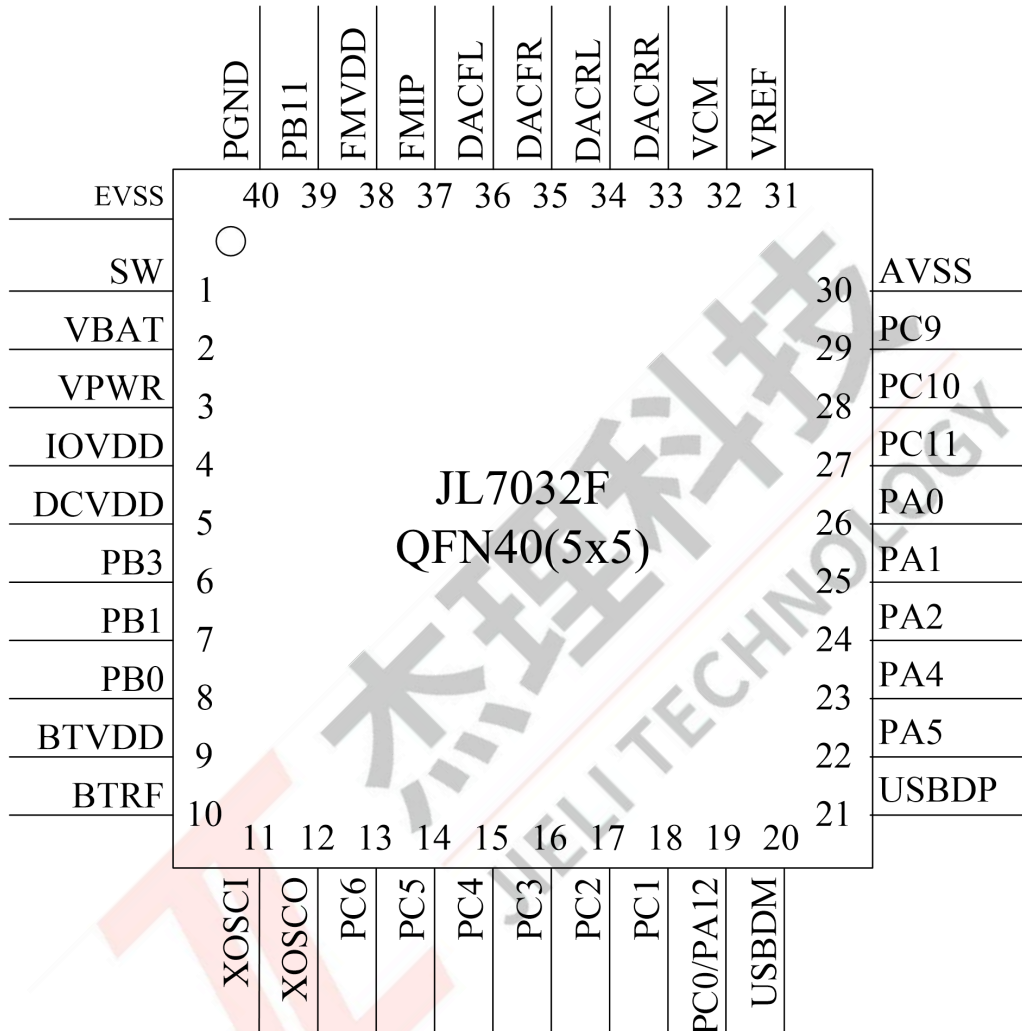


Figure 2-1 JL7032F Pin Assignment

2.2 Pin Description

Table 2-2-1 JL7032F Pin Description

Pin No.	Name	Type	IO Initial State	Description
1	SW	P	--	Buck DCDC Switch Port
2	VBAT	P	--	Battery Input
3	VPWR	I/O	Z	Charge Power Input
4	IOVDD	P	--	IO Power
5	DCVDD	P	--	DCDC power
6	PB3	I/O	Z	ADC6(ADC Input Channel 6) LP_TOUCHA2(TOUCH_CHA2) NFC_TX
7	PB1	I/O	10kΩ Pull-up	Hold down 0 to reset ADC5(ADC Input Channel 5) LP_TOUCHA0(TOUCH_CHA0)
8	PB0	I/O	Z	--
9	BTVDD	P	--	BT Power
10	BTRF	RF	--	Bluetooth RF Antenna
11	XOSCI	I	--	Crystal Oscillator Input
12	XOSCO	O	--	Crystal Oscillator Output
13	PC6	I/O	10kΩ Pull-up	ADC15(ADC Input Channel 15) LCD SEG19
14	PC5	I/O	Z	ADC14(ADC Input Channel 14) LCD COM0 PSRAM_D3A
15	PC4	I/O	Z	ADC13(ADC Input Channel 13) LCD COM1 PSRAM_CKA
16	PC3	I/O	Z	ADC12(ADC Input Channel 12) LCD COM2 PSRAM_CSA
17	PC2	I/O	Z	ADC11(ADC Input Channel 11) LCD COM3 LCD SEG18 PSRAM_D1A
18	PC1	I/O	Z	LCD COM4 LCD SEG17 PSRAM_D2A
19	PC0	I/O	Z	LCD COM5 LCD SEG16 PSRAM_D0A

Pin No.	Name	Type	IO Initial State	Description
	PA12	I/O	Z	ADC4(ADC Input Channel 4) LCD SEG12 PSRAM_D3B
20	USBDM	I/O	15kΩ Pull-down	USB Negative Data
21	USBDP	I/O	15kΩ Pull-down	USB Positive Data
22	PA5	I/O	Z	ADC1(ADC Input Channel 1) LCD SEG5 PAP_D3 MICBIASD(MIC Bias Output)
23	PA4	I/O	Z	LCD SEG4 PAP_D2 AIN_DN(Audio ADC Negative Input)
24	PA2	I/O	Z	ADC0(ADC Input Channel 0) LCD SEG2 PAP_D0 AIN_D0(Audio ADC Positive Input)
25	PA1	I/O	Z	LCD SEG1 AIN_B2(Audio ADC Positive Input) MICBIASB(MIC Bias Output)
26	PA0	I/O	Z	LCD SEG0 AIN_A2(Audio ADC Positive Input) MICBIASA(MIC Bias Output)
27	PC11	I/O	Z	LCD SEG24 AIN_CON(Audio ADC Negative Input)
28	PC10	I/O	Z	LCD SEG23 AIN_C1(Audio ADC Positive Input) MICBIASC(MIC Bias Output)
29	PC9	I/O	Z	LCD SEG22 AIN_C0(Audio ADC Positive Input)
30	AVSS	G	--	Audio Ground
31	VREF	P	--	Audio Power
32	VCM	P	--	Audio Reference Voltage
33	DACRR	O	--	Rear Right Channel DAC Output
34	DACRL (VCMO)	O	--	Rear Left Channel DAC Output Audio Common-mode Output voltage
35	DACFR	O	--	Front Right Channel DAC Output
36	DACFL	O	--	Front Left Channel DAC Output
37	FMIP	RF	--	FM Positive Input
38	FMVDD	P	--	FM Power

Pin No.	Name	Type	IO Initial State	Description
39	PB11	I/O	Z	ADC10(ADC Input Channel 10) SD Power FM_TX_B
40	PGND	P	--	Ground of Buck DC-DCc onverter

Note

- 1.IO initial state abbreviations Z--High resistance, H--High level, L--Low level, X--May be changed during power on.
- 2.Timer, MCPWM, QDEC, UART, LEDC, I²C, I²S, SPI,IR RX and SD functions can be remapped to any I/O.
- 3.PC6 input can not be Low in power on.

Table 2-2-2 Pin Types Description

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
G	Ground	I	Input
RF	RF antenna	O	Output

3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1 Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-20	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	4.5	V
VPWR		-0.3	6	V
IOVDD		-0.3	3.6	V
DCVDD		-0.3	1.4	V
BTVD		-0.3	3	V
FMVDD		-0.3	3.6	V
GPIO	Input voltage of GPIO (except PB0)	-0.3	3.6	V
HVTIO	Input voltage of HVT-IO (PB0)	-0.3	6	V

Note

1. Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device.

3.2 ESD Ratings

Table 3-2 ESD Ratings

Parameter	Typ	Test pin	Reference standard
Human Body Mode	±4kV	All pins	JEDEC EIA/JESD22-A114
Machine Mode	±400V	All pins	JEDEC EIA/JESD22-A115
Charge Device Model	±1kV	All pins	ANSI/ESDA/JEDEC JS-002-2022

3.3 PMU Characteristics

Table 3-3 PMU Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
VBAT	Voltage Input	--	2.7	3.7	4.5	V
VPWR	Charger supply Voltage	--	4.5	5.0	5.5	V
Operating mode						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Voltage output	VBAT = 4.2V, 10mA loading	--	3	--	V
	Loading current	IOVDD=3.0V@VBAT = 3.7V or VPWR=5V	--	--	300	mA
DCVDD	Voltage output	--	--	1.2	--	V
	Loading current	DCVDD=1.2V@IOVDD=3.0V on LDO mode	--	--	150	mA
		DCVDD=1.2V@VBAT=3.7V	--	--	180	mA

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
		on DCDC mode				
Low Power mode						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Loading current	IOVDD=3.0V@VBAT = 3.7V	--	--	20	mA

3.4 Battery Charge

Table 3-4 Charger Characteristics

Symbol	Parameter	Min	Typ	Max	Unit
VPWR	Charge Input Voltage	4.5	5	5.5	V
CV	CV Mode Voltage Accuracy	4.175	4.2	4.225	V
		4.325	4.35	4.375	V
CC	CC Mode Current	15	--	350	mA
I _{end}	End Of Charge Current	1.5	--	35	mA
V _{Trickl}	Trickle Charge Voltage	--	3	--	V

3.5 IO Characteristics

Table 3-5 IO Characteristics

Input Characteristics						
Symbol	Parameter	Conditions	IO	Min	Max	Unit
V _{IL}	Low-Level Input Voltage	IOVDD = 3.0V	PA0~PA4,PA5,PA12 PB0,PB1,PB3 PC0~PC6,PC9~PC11 USBDP USBDM VPWR	-0.3	1.4	V
V _{IH}	High-Level Input Voltage	IOVDD = 3.0V	PA0~PA4,PA5,PA12 PB1,PB3 PC0~PC6,PC9~PC11 USBDP USBDM	1.7	3.3	V
		IOVDD = 3.0V	PB0 VPWR	1.7	5.5	V
Output Characteristics						
Symbol	Parameter	Conditions	IO	Typ		Unit
I _{OL}	Output Current	IOVDD = 3.0V Voutput = 0.3V	PA0~PA4,PA5,PA12 PB1,PB3 PC0~PC6,PC9~PC11	2(HD=0) 8(HD=1) 26(HD=2) 50(HD=3)		mA
			PB0	8		mA

			USBDP USBDM		
			VPWR	2	mA
I _{OH}	Output Current	IOVDD = 3.0V Voutput = 2.7V	PA0~PA4,PA5,PA12 PB1,PB3 PC0~PC6,PC9~PC11	2(HD=0) 8(HD=1) 26(HD=2) 50(HD=3)	mA
			PB0 USBDP USBDM	8	mA
			VPWR	2	mA
			Internal Resistance Characteristics		
Symbol	Parameter	Conditions	IO	Typ	Unit
R _{pu}	Pull-up Resistance	IOVDD = 3.0V	PA0~PA4,PA5,PA12 PB0,PB1,PB3 PC0~PC6,PC9~PC11 VPWR	10k(PU=1) 100k(PU=2) 1M(PU=3)	Ω
			USBDP USBDM	1.5k(PU=1) 1k(PU=3)	Ω
R _{pd}	Pull-down Resistance	IOVDD = 3.0V	PA0~PA4,PA5,PA12 PB0,PB1,PB3 PC0~PC6,PC9~PC11 VPWR	10k(PD=1) 100k(PD=2) 1M(PD=3)	Ω
			USBDP USBDM	15k(PD=1)	Ω

Note

1.Internal pull-up/pull-down resistance accuracy ±20%.

3.6 Audio DAC Characteristics

Table 3-6 Stereo DAC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Resolution	--	--	--	24	bit
Output Sample Rate	--	8	--	96	kHz
SNR ^①	Differential Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	113	--	dB
	VCMO Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	107	--	dB
	Single-ended Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	110	--	dB
Dynamic Range	Differential Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	109	--	dB
	VCMO Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	104	--	dB
	Single-ended Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	106	--	dB
THD+N	Differential Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=32Ω	--	-86	--	dB
	VCMO Mode Fin=1kHz@0dBFS	--	-85	--	dB

	Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=32Ω				
	Single-ended Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=32Ω	--	-86	--	dB
Noise Floor	Differential Mode B/W=20Hz~20kHz A-Weighted load=10kΩ	--	7	--	uVrms
	VCMO Mode B/W=20Hz~20kHz A-Weighted load=10kΩ	--	6	--	uVrms
	Single-ended Mode B/W=20Hz~20kHz A-Weighted load=10kΩ	--	5	--	uVrms
Noise Floor with MUTE	Differential Mode B/W=20Hz~20kHz A-Weighted load=10kΩ	--	4	--	uVrms
	VCMO Mode B/W=20Hz~20kHz A-Weighted load=10kΩ	--	4	--	uVrms
	Single-ended Mode B/W=20Hz~20kHz A-Weighted load=10kΩ	--	3	--	uVrms
Stereo Crosstalk	VCMO Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	-108	--	dB
	Single-ended Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=10kΩ	--	-108	--	dB
Max Output Power	Differential Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=16Ω THD+N<0.1%	--	30	85	mW
	VCMO Mode	--	30	38	mW

	Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=16Ω THD+N<0.1%				
	Single-ended Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted load=16Ω THD+N<0.1%	--	30	38	mW

Note

1. ① SNR is the ratio of output level with a 1kHz full-scale input to output level with MUTE on.

3.7 Audio ADC Characteristics

Table 3-7 Audio ADC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Resolution	--	--	--	24	bits
Input Sample Rate	--	8	--	48	kHz
SNR	Differential input Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC gain=0dB	--	105	--	dB
	Single-ended input Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC gain=0dB	--	102	--	dB
Dynamic Range	Differential input Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC gain=0dB	--	105	--	dB
	Single-ended input Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC gain=0dB	--	102	--	dB
THD+N	Differential input Mode Fin=1kHz@0dBFS Fs=44.1kHz	--	-90	--	dB

Parameter	Conditions	Min	Typ	Max	Unit
	B/W=20Hz~20kHz A-Weighted ADC gain=0dB				
	Single-ended input Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC gain=0dB	--	-90	--	dB
Analogue Gain	--	-6	--	28	dB
Max Input Level	Differential input Mode ADC gain=0dB	--	2	--	Vrms
	Single-ended input Mode ADC gain=0dB	--	1	--	Vrms

3.8 BT Characteristics

3.8.1 Transmitter

Table 3-8-1 Transmitter characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Maximum RF Transmit Power	BR	--	10	--	dBm
Maximum RF Transmit Power	EDR $\pi/4$ DQPSK EDR 8DPSK	--	10	--	dBm
Relative Transmit Power	EDR $\pi/4$ DQPSK EDR 8DPSK	--	-3	--	dB
Maximum RF Transmit Power	BLE-1Mbps	--	10	--	dBm

3.8.2 Receiver

Table 3-8-2 Receiver characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Sensitivity	BR	--	-95	--	dBm
	EDR $\pi/4$ DQPSK	--	-95	--	dBm
	EDR 8DPSK	--	-87	--	dBm
	BLE-1Mbps	--	-98.5	--	dBm
	BLE-2Mbps	--	-95.5	--	dBm
	BLE-S2	--	-101	--	dBm
	BLE-S8	--	-106	--	dBm

3.9 FM Characteristics

Table 3-9-1 FM Receiver Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Frequency range	--	64	--	108	MHz
RF Mono sensitivity	(S+N)/N=26dB	--	4	--	dBuV
Mono Audio SNDR	--	--	75	--	dB
Stereo Audio SNDR	--	--	64	--	dB
Stereo channel separation	--	--	54	--	dB

4 Package Information

4.1 QFN40_5x5mm

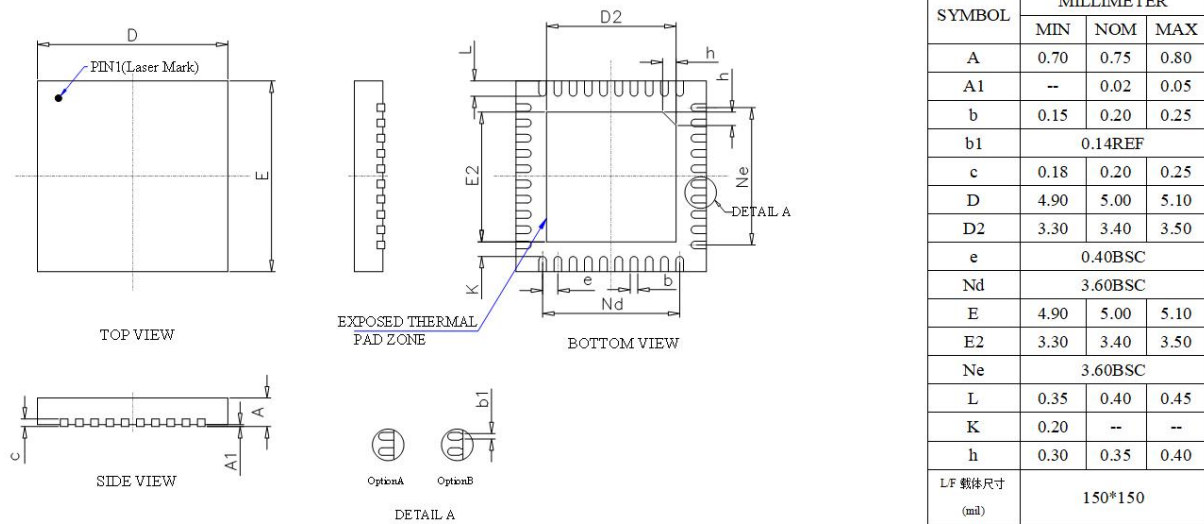


Figure 4-1 JL7032F Package

5 IC Marking Information

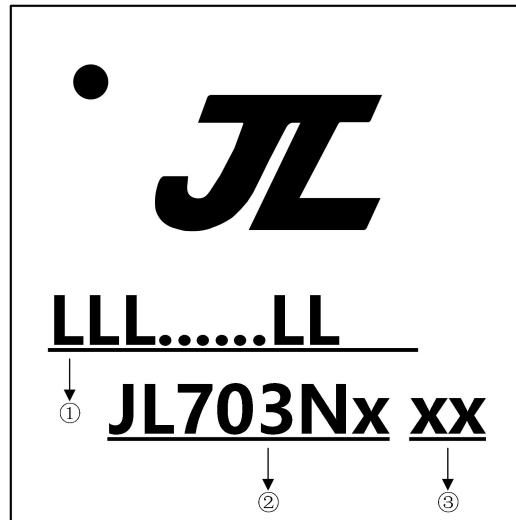


Figure 5-1 JL7032F Package Outline

- ① LLL.....LL LOT No. , It contains 7 to 18 alphanumerics
 - ② JL703Nx Chip Model
 - ③ xx Built-in Memory
 - 0 No Flash Memory
 - 2 2Mbit Flash
 - 4 4Mbit Flash
 - 8 8Mbit Flash
 - 6 16Mbit Flash
 - 3 32Mbit Flash
- nS memory is flash plus PSRAM, n represents the flash capacity, S represents 16Mbit PSRAM
nT memory is flash plus PSRAM, n represents the flash capacity, T represents 64Mbit PSRAM

6 Solder-Reflow Condition

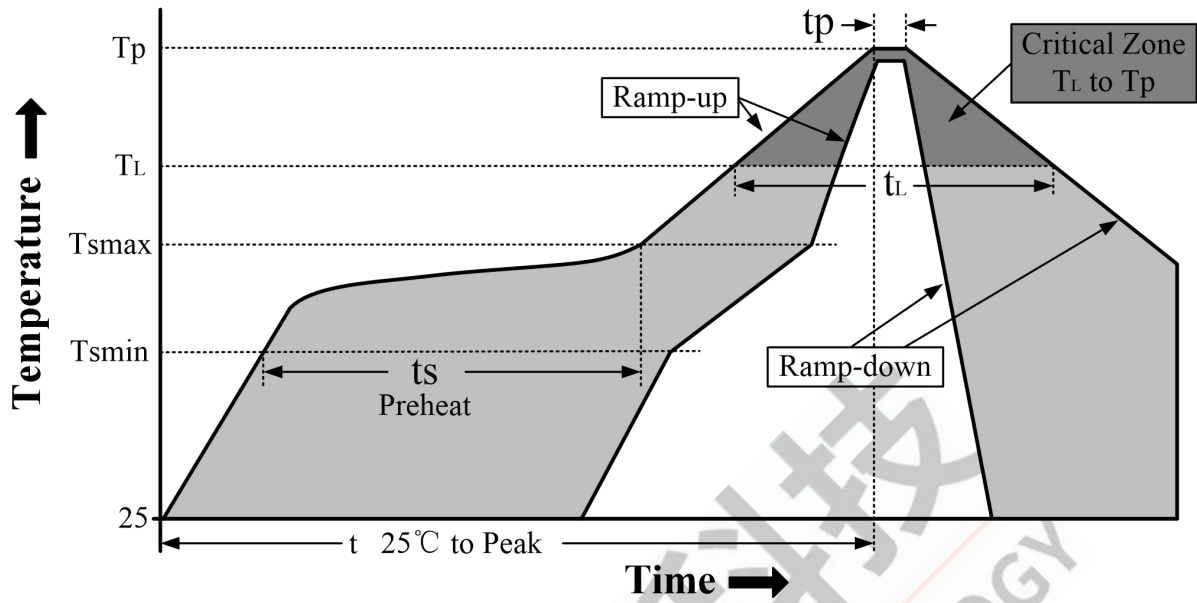


Figure 6-1 Classification Reflow Profile

Table 6-1 Classification Profiles

Profile Feature		Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat/Soak	Temperature Min (T_{smin})	100°C	150°C
	Temperature Max (T_{smax})	150°C	200°C
	Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-180 seconds
Average ramp-up rate (T_{smax} to T_p)		3°C/second max	3°C/second max
Liquidous temperature (T_L)		183°C	217°C
Time (t_L) maintained above T_L		60-150 seconds	60-150 seconds
Peak package body temperature (T_p)		See Table 6-2	See Table 6-3
Time within 5°C of actual Peak Temperature (t_p) ²		10-30 seconds	20-40 seconds
Ramp-down rate (T_p to T_L)		6°C/second max	6°C/second max
Time 25°C to peak temperature		6 minutes max	8 minutes max

Note

- 1.All temperatures refer to topside of the package, measured on the package body surface
- 2.Time within 5°C of actual peak temperature (t_p) specified for the reflow profiles is a "supplier" and "user" maximum.

Table 6-2 SnPb Classification Temperature

Package Thickness	Volume mm ³ < 350	Volume mm ³ ≥ 350
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C

Table 6-3 Pb-free - Classification Temperature

Package Thickness	Volume mm ³ < 350	Volume mm ³ 350 - 2000	Volume mm ³ > 2000
< 1.6mm	260°C	260°C	260°C
1.6 mm - 2.5mm	260°C	250°C	245°C
> 2.5mm	250°C	245°C	245°C

Note

1.*Tolerance The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C.For example 260°C+0°C)at the rated MSL level.